IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re I	Patent Application of:)	Group Art Unit: 2811
	Osamu Goto, et al.)	Examiner: Ori Nadav
Appli	cation No. 10/606,176)	Confirmation No.: 3458
Filed:	June 25, 2003)	
For:	SEMICONDUCTOR LIGHT EMITTING DEVICE, ITS MANUFACTURING METHOD, SEMICONDUCTOR DEVICE AND ITS MANUFACTURING METHOD)))	
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TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT BEFORE MAILING DATE OF EITHER A FINAL ACTION OR NOTICE OF ALLOWANCE (37 C.F.R. § 1.97(c))

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The information disclosure statement transmitted herewith is being filed *after*: (1) three months of the filing date of a national application other than a continued prosecution application under § 1.53(d); (2) three months of the date of entry of the national stage as set forth in § 1.491 in an international application; (3) the mailing of a first Office action on the merits; or (4) the mailing of a first Office action after the filing of a request for continued examination under § 1.114; but *before* the mailing date of any of a final action under § 1.113, a notice of allowance under § 1.311, or an action that otherwise closes prosecution in the application, whichever occurs first.

Application No. 10/606,176

Transmittal of Information Disclosure Statement

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Applicants submit the \$180.00 fee set forth in 37 C.F.R. § 1.17(p) for submission of an

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Respectfully submitted,

Dated: August 25, 2006

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		Application Number	10/606,176	
_	DRMATION DISCLOSURE	Filing Date	June 25, 2003	
STATEMENT BY APPLICANT		First Named Inventor	Yoshihide Nakamura	
		Art Unit	2811	
	(use as many sheets as necessary)	Examiner Name	Ori Nadav	
Sheet of		Attorney Docket Number	09792909-5625	
	U.S. P	ATENT DOCUMENTS		

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		US-6,309,459	10-	30-2001	Shozo Yuge			
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Substitute for form 1449B/PTO		Complete if Known			
		Application Number	10/606,176		
INFORMATION DISCLOSURE			Filing Date	June 25, 2003	
STATEMENT BY APPLICANT (use as many sheets as necessary)		First Named Inventor	Yoshihide Nakamura		
		Art Unit	2811		
		Examiner Name	Ori Nadav		
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	"InGaN Multi-Quantum-Well-Structure Laser Diodes with Cleaved Mirror Cavity Facets," Jpn. J. Appl. Phys., Vol. 35, 1996, pp. L217-L220	
	"Blue InGaN-Based Laser Diodes with an Emission Wavelength of 450nm" Appl. Phys. Lett., Vol. 76, 2000, pp. 22-24	
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	"High-Power, Long-Lifetime InGaN/GaN/AlGaN-Based Laser Diodes Grown on Pure GaN Substrates." Jpn. J. Appl. Phys., Vol. 35, 1998, pp. L309-L312	
	"InGaN/GaN/AlGaN-Based Laser Diodes Grown on Epitaxially Laterally Overgrown GaN," J. Mater. Res., Vol. 14, No. 7, 1999, pp. 2716-2731	
	"InGaN/GaN/AlGaN-Based Laser Diodes with Modulation-Doped Strained- Layer Superlattices," Jpn. J. Appl. Phys., Vol. 36, 1997, pp. 1568-1571	
		item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published. "InGaN Multi-Quantum-Well-Structure Laser Diodes with Cleaved Mirror Cavity Facets," Jpn. J. Appl. Phys., Vol. 35, 1996, pp. L217-L220 "Blue InGaN-Based Laser Diodes with an Emission Wavelength of 450nm" Appl. Phys. Lett., Vol. 76, 2000, pp. 22-24 "Fist III-V-Nitride-Based Violet Laser Diodes" J. Crystal Growth, Vol. 170, 1997, pp. 11-15 "High-Power, Long-Lifetime InGaN/GaN/AlGaN-Based Laser Diodes Grown on Pure GaN Substrates." Jpn. J. Appl. Phys., Vol. 35, 1998, pp. L309-L312 "InGaN/GaN/AlGaN-Based Laser Diodes Grown on Epitaxially Laterally Overgrown GaN," J. Mater. Res., Vol. 14, No. 7, 1999, pp. 2716-2731 "InGaN/GaN/AlGaN-Based Laser Diodes with Modulation-Doped Strained-

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